# 2SD0874, 2SD0874A (2SD874, 2SD874A)

## Silicon NPN epitaxial planar type

For low-frequency power amplification Complementary to 2SB0766 (2SB766) and 2SB0766A (2SB766A)

### ■ Features

- Large collector power dissipation P<sub>C</sub>
- ullet Low collector-emitter saturation voltage  $V_{CE(sat)}$
- Mini power type package, allowing downsizing of the equipment and automatic insertion through the tape packing and the magazine packing

## ■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter	Symbol	Rating	Unit	
Collector-base voltage	2SD0874	V <sub>CBO</sub>	30	V
(Emitter open)	2SD0874A		60	
Collector-emitter voltage	2SD0874	V <sub>CEO</sub>	25	V
(Base open)	2SD0874A		50	
Emitter-base voltage (Coll	V <sub>EBO</sub>	5	V	
Collector current	$I_{C}$	1	A	
Peak collector current	$I_{CP}$	1.5	A	
Collector power dissipation	P <sub>C</sub>	1	W	
Junction temperature	Tj	150	°C	
Storage temperature	$T_{stg}$	-55 to +150	°C	

Note) \*: Printed circuit board: Copper foil area of 1 cm<sup>2</sup> or more, and the board thickness of 1.7 mm for the collector portion

# Unit: mm 4.5±0.1 1.6±0.2 1.5±0.0 1.

## Marking Symbol:

2SD0874: Z2SD0874A: Y

## ■ Electrical Characteristics $T_a = 25$ °C $\pm 3$ °C

Parameter		Symbol	Conditions	Min	Тур	Max	Unit
Collector-base voltage	2SD0874	$V_{CBO}$	$I_C = 10 \mu\text{A}, I_E = 0$	30	5		V
(Emitter open)	2SD0874A	OLE.	80 (01) (2)	60			
Collector-emitter voltage	2SD0874	V <sub>CEO</sub>	$I_C = 2 \text{ mA}, I_B = 0$	25			V
(Base open)	2SD0874A		d. sills ich	50			
Emitter-base voltage (Colle	ctor open)	$V_{EBO}$	$I_E = 10 \mu\text{A},  I_C = 0$	5			V
Collector-base cutoff current (Emitter open)		$I_{CBO}$	$V_{CB} = 20 \text{ V}, I_{E} = 0$			0.1	μΑ
Forward current transfer ratio *1		h <sub>FE1</sub> *2	$V_{CE} = 10 \text{ V}, I_{C} = 500 \text{ mA}$	85		340	_
Mis		h <sub>FE2</sub>	$V_{CE} = 5 V, I_{C} = 1 A$	50			
Collector-emitter saturation voltage *1		V <sub>CE(sat)</sub>	$I_C = 500 \text{ mA}, I_B = 50 \text{ mA}$		0.2	0.4	V
Base-emitter saturation voltage *1 V		V <sub>BE(sat)</sub>	$I_C = 500 \text{ mA}, I_B = 50 \text{ mA}$		0.85	1.2	V
Transition frequency		$f_T$	$V_{CB} = 10 \text{ V}, I_E = -50 \text{ mA}, f = 200 \text{ MHz}$		200		MHz
Collector output capacitance		C <sub>ob</sub>	$V_{CB} = 10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$			20	pF
(Common base, input open circuited)							

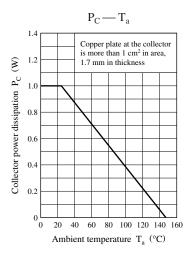
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

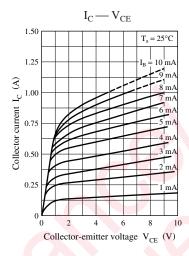
2. \*1: Pulse measurement

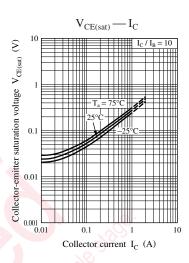
\*2: Rank classification

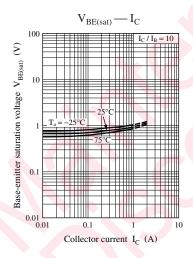
Rank	Q	R	S
$h_{FE1}$	85 to 170	120 to 240	170 to 340

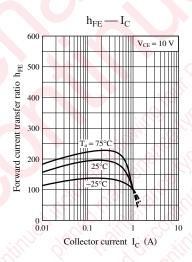
Note) The part numbers in the parenthesis show conventional part number.

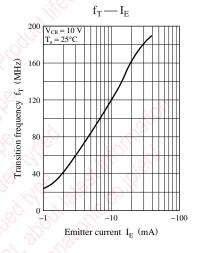


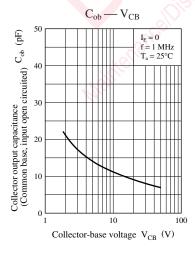


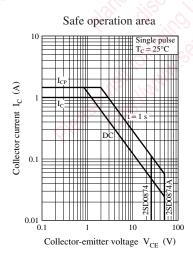












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